500V PNP HIGH PERFORMANCE TRANSISTOR IN SOT223

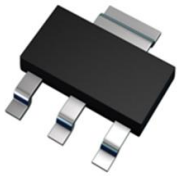
Features

- BV_{CEO} > -500V
- I_C = -150mA High Continuous Current
- I_{CM} = -500mA Peak Pulse Current
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **An Automotive-Compliant Part is Available Under Separate Datasheet (ZXTP01500BGQ)**

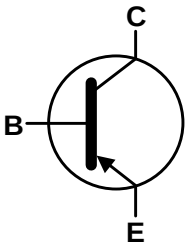
Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.112 grams (Approximate)

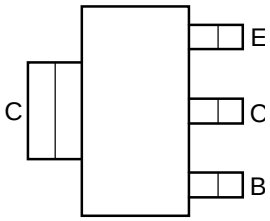
SOT223



Top View



Device Symbol



Top View
Pin-Out

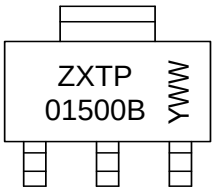
Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTP01500BGTA	AEC-Q101	ZXTP 01500B	13	12	1,000
ZXTP01500BGTC	AEC-Q101	ZXTP 01500B	13	12	4,000

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

SOT223



ZXTP01500B = Product Type Marking Code
YWW = Date Code Marking
Y or $\overline{Y}$ = Last Digit of Year (ex: 7 = 2017)
WW or $\overline{WW}$ = Week Code (01 to 53)

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Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	-500	V
Collector-Emitter Voltage	V_{CEO}	-500	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	I_C	-150	mA
Peak Pulse Current	I_{CM}	-500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P_D	2	W
	(Note 6)		3	W
Thermal Resistance, Junction to Ambient	(Note 5)	$R_{\theta JA}$	62.5	°C/W
	(Note 6)		41.7	°C/W
Thermal Resistance, Junction to Leads	(Note 7)	$R_{\theta JL}$	14.8	°C/W
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	°C

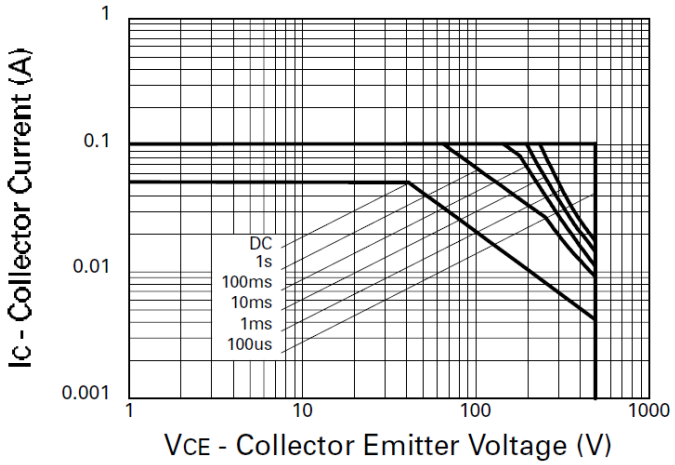
ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

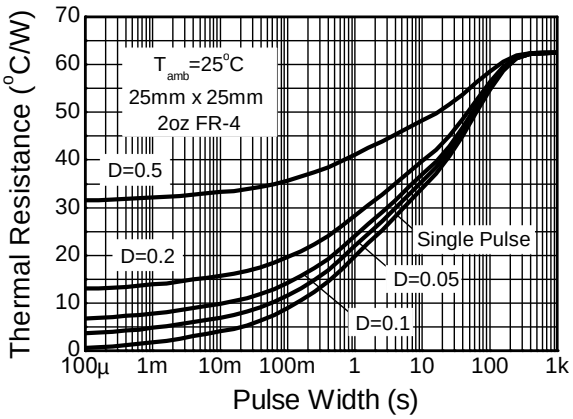
Notes:
5. For a device mounted with the collector lead on 25mm x 25mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in steady-state.
6. Same as note (5), except the device is mounted on 50mm x 50mm 2oz copper.
7. Thermal resistance from junction to solder-point (at the end of the collector lead).
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

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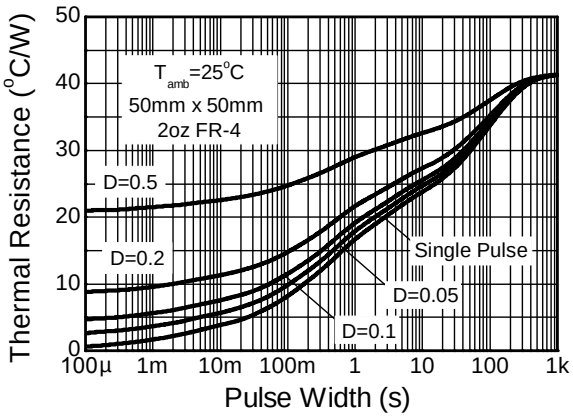
Thermal Characteristics and Derating Information



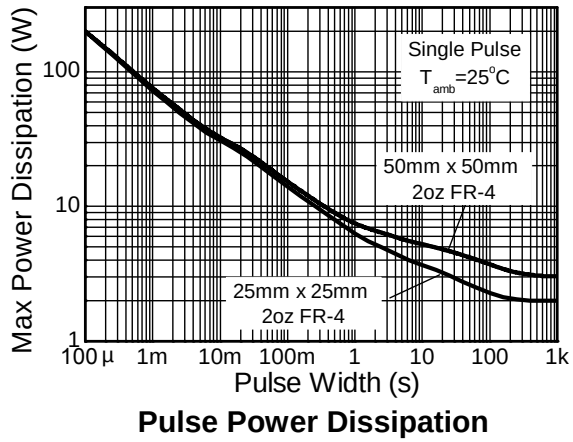
Safe Operating Area



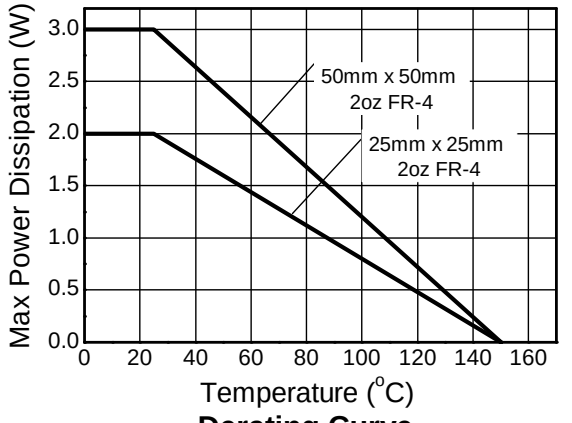
Transient Thermal Impedance



Transient Thermal Impedance



Pulse Power Dissipation



Derating Curve

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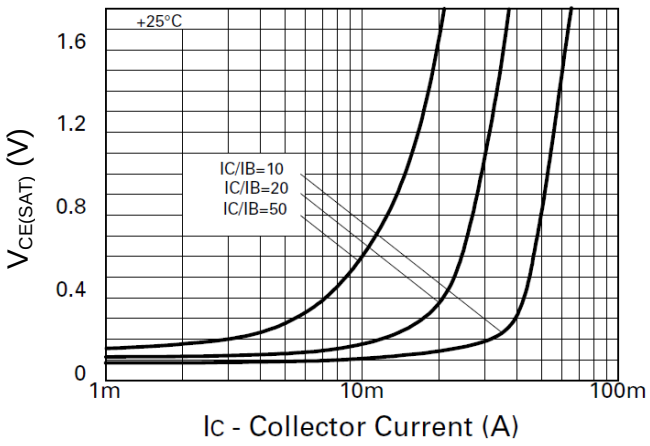
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-500	—	—	V	I_C = -100µA
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	-500	—	—	V	I_C = -1mA
Emitter-Base Breakdown Voltage	BV_{EBO}	-7	—	—	V	I_E = -100µA
Collector Cut-off Current	I_{CBO}	—	—	-100	nA	V_{CB} = -500V
Collector Cut-off Current	I_{CES}	—	—	-100	nA	V_{CE} = -500V
Emitter Cut-off Current	I_{EBO}	—	—	-100	nA	V_{EB} = -5.6V
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(SAT)}$	—	—	-200	mV	I_C = -20mA, I_B = -2mA
		—	—	-500		I_C = -50mA, I_B = -10mA
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(SAT)}$	—	—	-900	mV	I_C = -50mA, I_B = -10mA
Base-Emitter Turn-On Voltage (Note 9)	$V_{BE(ON)}$	—	—	-900	mV	I_C = -50mA, V_{CE} = -10V
DC Current Gain (Note 9)	h_{FE}	100	—	300	—	I_C = -1mA, V_{CE} = -10V
		80	—	300		I_C = -50mA, V_{CE} = -10V
		—	15	—		I_C = -100mA, V_{CE} = -10V
Current Gain-Bandwidth Product	f_T	60	—	—	MHz	V_{CE} = -20V, I_C = -10mA f = 50MHz
Turn-On Time	t_{ON}	—	110	—	ns	V_{CC} = -100V, I_C = -50mA
Turn-Off Time	t_{OFF}	—	1.5	—	µs	I_{B1} = -5mA, I_{B2} = 10mA
Output Capacitance	C_{OBO}	—	—	8	pF	V_{CB} = -20V, f = 1MHz

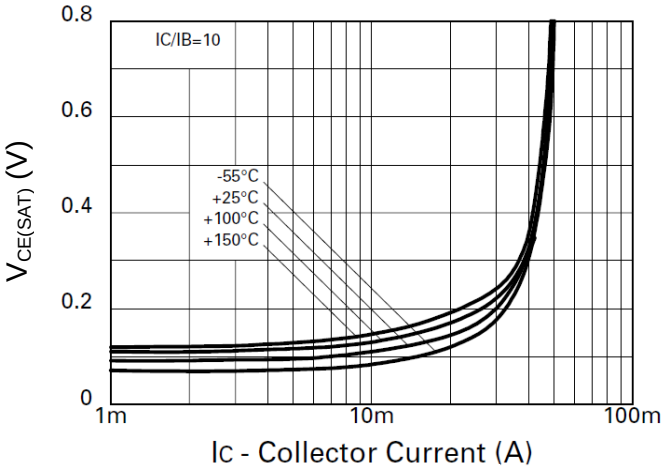
Note: 9. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.

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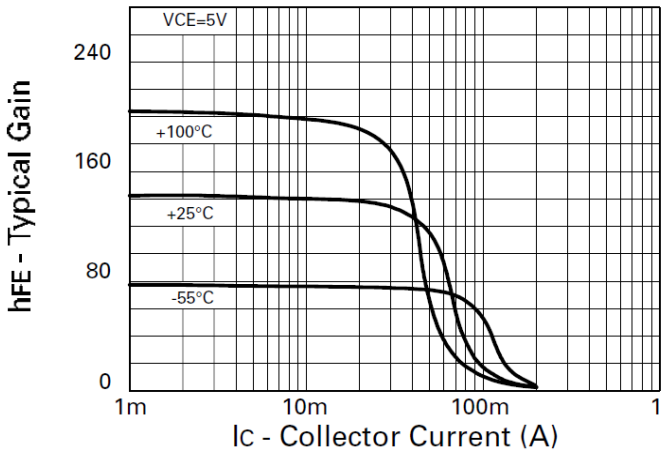
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)



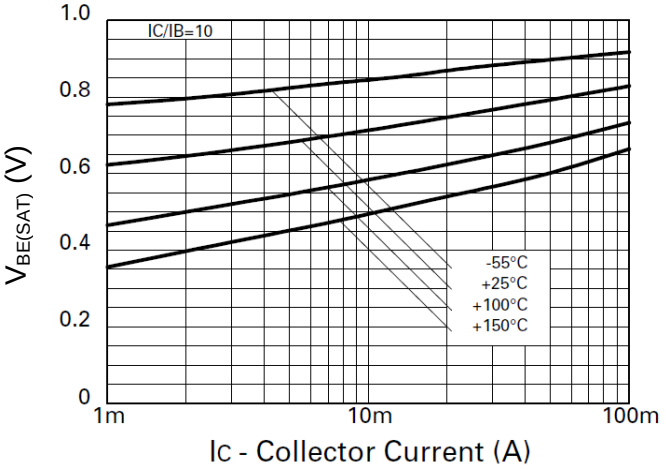
$V_{CE(SAT)}$ v I_C



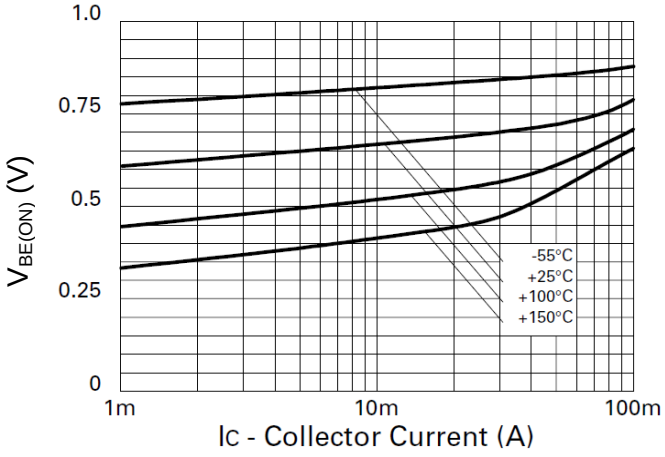
$V_{CE(SAT)}$ v I_C



hFE v IC



$V_{BE(SAT)}$ v I_C



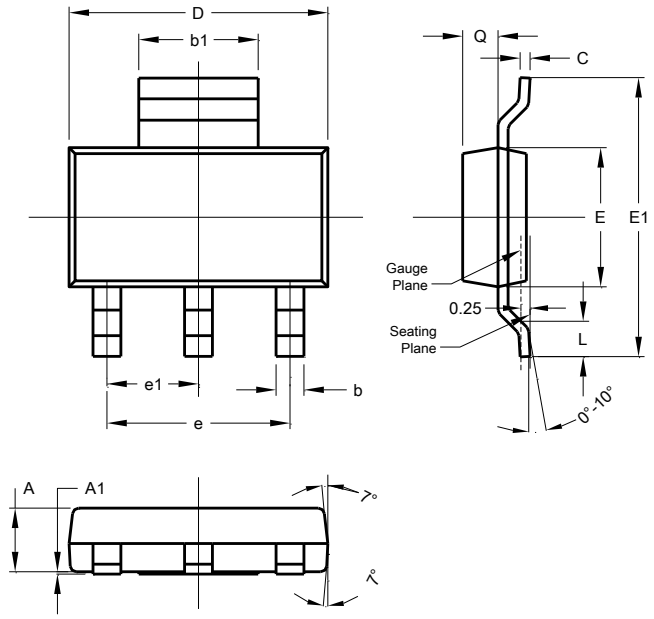
$V_{BE(ON)}$ v I_C

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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223

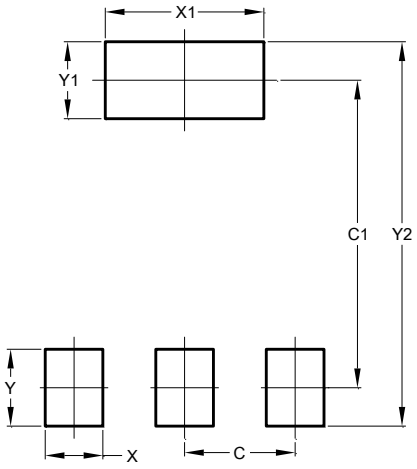


SOT223			
Dim	**Min**	**Max**	**Typ**
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT223



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.

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